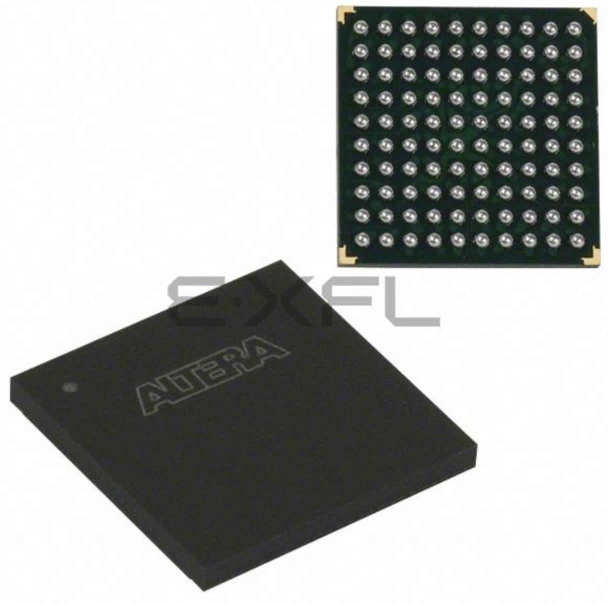
Intel - EPM7128AEFC100-7N Datasheet



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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	8
Number of Macrocells	128
Number of Gates	2500
Number of I/O	84
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LBGA
Supplier Device Package	100-FBGA (11x11)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epm7128aefc100-7n

- Software design support and automatic place-and-route provided by Altera's development systems for Windows-based PCs and Sun SPARCstation, and HP 9000 Series 700/800 workstations
- Additional design entry and simulation support provided by EDIF 2 0 0 and 3 0 0 netlist files, library of parameterized modules (LPM), Verilog HDL, VHDL, and other interfaces to popular EDA tools from manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplicity, and VeriBest
- Programming support with Altera's Master Programming Unit (MPU), MasterBlaster$^{\text{TM}}$ serial/universal serial bus (USB) communications cable, ByteBlasterMV$^{\text{TM}}$ parallel port download cable, and BitBlaster$^{\text{TM}}$ serial download cable, as well as programming hardware from third-party manufacturers and any Jam$^{\text{TM}}$ STAPL File (**.jam**), Jam Byte-Code File (**.jbc**), or Serial Vector Format File- (**.svf**) capable in-circuit tester

General Description

MAX 7000A (including MAX 7000AE) devices are high-density, high-performance devices based on Altera's second-generation MAX architecture. Fabricated with advanced CMOS technology, the EEPROM-based MAX 7000A devices operate with a 3.3-V supply voltage and provide 600 to 10,000 usable gates, ISP, pin-to-pin delays as fast as 4.5 ns, and counter speeds of up to 227.3 MHz. MAX 7000A devices in the -4, -5, -6, -7, and some -10 speed grades are compatible with the timing requirements for 33 MHz operation of the PCI Special Interest Group (PCI SIG) ***PCI Local Bus Specification, Revision 2.2***. See Table 2.

Table 2. MAX 7000A Speed Grades

Device	Speed Grade					
	-4	-5	-6	-7	-10	-12
EPM7032AE	✓			✓	✓	
EPM7064AE	✓			✓	✓	
EPM7128A			✓	✓	✓	✓
EPM7128AE		✓		✓	✓	
EPM7256A			✓	✓	✓	✓
EPM7256AE		✓		✓	✓	
EPM7512AE				✓	✓	✓

MAX 7000A devices use CMOS EEPROM cells to implement logic functions. The user-configurable MAX 7000A architecture accommodates a variety of independent combinatorial and sequential logic functions. The devices can be reprogrammed for quick and efficient iterations during design development and debug cycles, and can be programmed and erased up to 100 times.

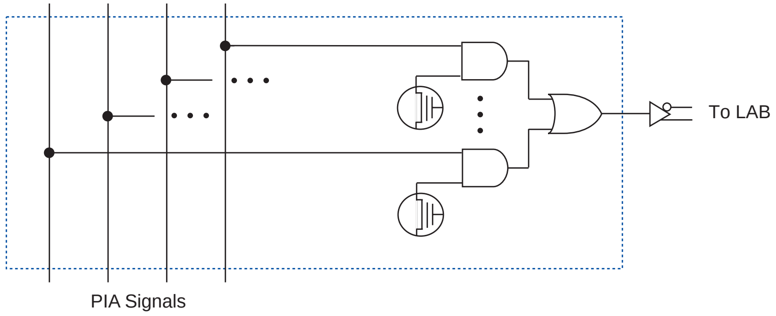
MAX 7000A devices contain from 32 to 512 macrocells that are combined into groups of 16 macrocells, called logic array blocks (LABs). Each macrocell has a programmable-`AND`/fixed-`OR` array and a configurable register with independently programmable clock, clock enable, clear, and preset functions. To build complex logic functions, each macrocell can be supplemented with both shareable expander product terms and high-speed parallel expander product terms, providing up to 32 product terms per macrocell.

MAX 7000A devices provide programmable speed/power optimization. Speed-critical portions of a design can run at high speed/full power, while the remaining portions run at reduced speed/low power. This speed/power optimization feature enables the designer to configure one or more macrocells to operate at 50% or lower power while adding only a nominal timing delay. MAX 7000A devices also provide an option that reduces the slew rate of the output buffers, minimizing noise transients when non-speed-critical signals are switching. The output drivers of all MAX 7000A devices can be set for 2.5 V or 3.3 V, and all input pins are 2.5-V, 3.3-V, and 5.0-V tolerant, allowing MAX 7000A devices to be used in mixed-voltage systems.

MAX 7000A devices are supported by Altera development systems, which are integrated packages that offer schematic, text—including VHDL, Verilog HDL, and the Altera Hardware Description Language (AHDL)—and waveform design entry, compilation and logic synthesis, simulation and timing analysis, and device programming. The software provides EDIF 2 0 0 and 3 0 0, LPM, VHDL, Verilog HDL, and other interfaces for additional design entry and simulation support from other industry-standard PC- and UNIX-workstation-based EDA tools. The software runs on Windows-based PCs, as well as Sun SPARCstation, and HP 9000 Series 700/800 workstations.

For more information on development tools, see the *MAX+PLUS II Programmable Logic Development System & Software Data Sheet* and the *Quartus Programmable Logic Development System & Software Data Sheet*.

Figure 5. MAX 7000A PIA Routing



While the routing delays of channel-based routing schemes in masked or FPGAs are cumulative, variable, and path-dependent, the MAX 7000A PIA has a predictable delay. The PIA makes a design's timing performance easy to predict.

I/O Control Blocks

The I/O control block allows each I/O pin to be individually configured for input, output, or bidirectional operation. All I/O pins have a tri-state buffer that is individually controlled by one of the global output enable signals or directly connected to ground or V_{CC}. Figure 6 shows the I/O control block for MAX 7000A devices. The I/O control block has 6 or 10 global output enable signals that are driven by the true or complement of two output enable signals, a subset of the I/O pins, or a subset of the I/O macrocells.

In-System Programmability

MAX 7000A devices can be programmed in-system via an industry-standard 4-pin IEEE Std. 1149.1 (JTAG) interface. ISP offers quick, efficient iterations during design development and debugging cycles. The MAX 7000A architecture internally generates the high programming voltages required to program EEPROM cells, allowing in-system programming with only a single 3.3-V power supply. During in-system programming, the I/O pins are tri-stated and weakly pulled-up to eliminate board conflicts. The pull-up value is nominally 50 kΩ.

MAX 7000AE devices have an enhanced ISP algorithm for faster programming. These devices also offer an ISP_Done bit that provides safe operation when in-system programming is interrupted. This ISP_Done bit, which is the last bit programmed, prevents all I/O pins from driving until the bit is programmed. This feature is only available in EPM7032AE, EPM7064AE, EPM7128AE, EPM7256AE, and EPM7512AE devices.

ISP simplifies the manufacturing flow by allowing devices to be mounted on a PCB with standard pick-and-place equipment before they are programmed. MAX 7000A devices can be programmed by downloading the information via in-circuit testers, embedded processors, the Altera MasterBlaster serial/USB communications cable, ByteBlasterMV parallel port download cable, and BitBlaster serial download cable. Programming the devices after they are placed on the board eliminates lead damage on high-pin-count packages (e.g., QFP packages) due to device handling. MAX 7000A devices can be reprogrammed after a system has already shipped to the field. For example, product upgrades can be performed in the field via software or modem.

In-system programming can be accomplished with either an adaptive or constant algorithm. An adaptive algorithm reads information from the unit and adapts subsequent programming steps to achieve the fastest possible programming time for that unit. A constant algorithm uses a pre-defined (non-adaptive) programming sequence that does not take advantage of adaptive algorithm programming time improvements. Some in-circuit testers cannot program using an adaptive algorithm. Therefore, a constant algorithm must be used. MAX 7000AE devices can be programmed with either an adaptive or constant (non-adaptive) algorithm. EPM7128A and EPM7256A device can only be programmed with an adaptive algorithm; users programming these two devices on platforms that cannot use an adaptive algorithm should use EPM7128AE and EPM7256AE devices.

The Jam Standard Test and Programming Language (STAPL), JEDEC standard JESD 71, can be used to program MAX 7000A devices with in-circuit testers, PCs, or embedded processors.

Programming Times

The time required to implement each of the six programming stages can be broken into the following two elements:

- A pulse time to erase, program, or read the EEPROM cells.
- A shifting time based on the test clock (`TCK`) frequency and the number of `TCK` cycles to shift instructions, address, and data into the device.

By combining the pulse and shift times for each of the programming stages, the program or verify time can be derived as a function of the `TCK` frequency, the number of devices, and specific target device(s). Because different ISP-capable devices have a different number of EEPROM cells, both the total fixed and total variable times are unique for a single device.

Programming a Single MAX 7000A Device

The time required to program a single MAX 7000A device in-system can be calculated from the following formula:

$$t_{PROG} = t_{PPULSE} + \frac{Cycle_{PTCK}}{f_{TCK}}$$

where: t_{PROG} = Programming time
t_{PPULSE} = Sum of the fixed times to erase, program, and verify the EEPROM cells
$Cycle_{PTCK}$ = Number of `TCK` cycles to program a device
f_{TCK} = `TCK` frequency

The ISP times for a stand-alone verification of a single MAX 7000A device can be calculated from the following formula:

$$t_{VER} = t_{VPULSE} + \frac{Cycle_{VTCK}}{f_{TCK}}$$

where: t_{VER} = Verify time
t_{VPULSE} = Sum of the fixed times to verify the EEPROM cells
$Cycle_{VTCK}$ = Number of `TCK` cycles to verify a device

The programming times described in Tables 5 through 7 are associated with the worst-case method using the enhanced ISP algorithm.

Table 5. MAX 7000A t_{PULSE} & $Cycle_{TCK}$ Values

Device	Programming		Stand-Alone Verification	
	t_{PPULSE} (s)	$Cycle_{PTCK}$	t_{VPULSE} (s)	$Cycle_{VTCK}$
EPM7032AE	2.00	55,000	0.002	18,000
EPM7064AE	2.00	105,000	0.002	35,000
EPM7128AE	2.00	205,000	0.002	68,000
EPM7256AE	2.00	447,000	0.002	149,000
EPM7512AE	2.00	890,000	0.002	297,000
EPM7128A *(1)*	5.11	832,000	0.03	528,000
EPM7256A *(1)*	6.43	1,603,000	0.03	1,024,000

Tables 6 and 7 show the in-system programming and stand alone verification times for several common test clock frequencies.

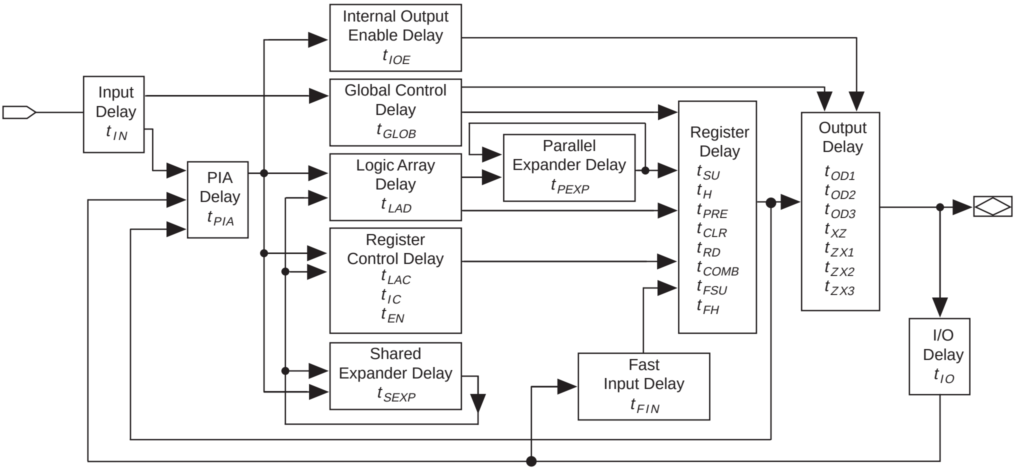
Table 6. MAX 7000A In-System Programming Times for Different Test Clock Frequencies

Device	f_{TCK}								Units
	10 MHz	5 MHz	2 MHz	1 MHz	500 kHz	200 kHz	100 kHz	50 kHz	
EPM7032AE	2.01	2.01	2.03	2.06	2.11	2.28	2.55	3.10	s
EPM7064AE	2.01	2.02	2.05	2.11	2.21	2.53	3.05	4.10	s
EPM7128AE	2.02	2.04	2.10	2.21	2.41	3.03	4.05	6.10	s
EPM7256AE	2.05	2.09	2.23	2.45	2.90	4.24	6.47	10.94	s
EPM7512AE	2.09	2.18	2.45	2.89	3.78	6.45	10.90	19.80	s
EPM7128A *(1)*	5.19	5.27	5.52	5.94	6.77	9.27	13.43	21.75	s
EPM7256A *(1)*	6.59	6.75	7.23	8.03	9.64	14.45	22.46	38.49	s

Table 15. MAX 7000A Device DC Operating Conditions *Note (6)*					
Symbol	**Parameter**	**Conditions**	**Min**	**Max**	**Unit**
V_{IH}	High-level input voltage		1.7	5.75	V
V_{IL}	Low-level input voltage		–0.5	0.8	V
V_{OH}	3.3-V high-level TTL output voltage	I_{OH} = –8 mA DC, V_{CCIO} = 3.00 V *(7)*	2.4		V
	3.3-V high-level CMOS output voltage	I_{OH} = –0.1 mA DC, V_{CCIO} = 3.00 V *(7)*	V_{CCIO} – 0.2		V
	2.5-V high-level output voltage	I_{OH} = –100 µA DC, V_{CCIO} = 2.30 V *(7)*	2.1		V
		I_{OH} = –1 mA DC, V_{CCIO} = 2.30 V *(7)*	2.0		V
		I_{OH} = –2 mA DC, V_{CCIO} = 2.30 V *(7)*	1.7		V
V_{OL}	3.3-V low-level TTL output voltage	I_{OL} = 8 mA DC, V_{CCIO} = 3.00 V *(8)*		0.45	V
	3.3-V low-level CMOS output voltage	I_{OL} = 0.1 mA DC, V_{CCIO} = 3.00 V *(8)*		0.2	V
	2.5-V low-level output voltage	I_{OL} = 100 µA DC, V_{CCIO} = 2.30 V *(8)*		0.2	V
		I_{OL} = 1 mA DC, V_{CCIO} = 2.30 V *(8)*		0.4	V
		I_{OL} = 2 mA DC, V_{CCIO} = 2.30 V *(8)*		0.7	V
I_I	Input leakage current	V_I = –0.5 to 5.5 V *(9)*	–10	10	µA
I_{OZ}	Tri-state output off-state current	V_I = –0.5 to 5.5 V *(9)*	–10	10	µA
R_{ISP}	Value of I/O pin pull-up resistor during in-system programming or during power-up	V_{CCIO} = 3.0 to 3.6 V *(10)*	20	50	kΩ
		V_{CCIO} = 2.3 to 2.7 V *(10)*	30	80	kΩ
		V_{CCIO} = 2.3 to 3.6 V *(11)*	20	74	kΩ

Table 16. MAX 7000A Device Capacitance *Note (12)*					
Symbol	**Parameter**	**Conditions**	**Min**	**Max**	**Unit**
C_{IN}	Input pin capacitance	V_{IN} = 0 V, f = 1.0 MHz		8	pF
$C_{I/O}$	I/O pin capacitance	V_{OUT} = 0 V, f = 1.0 MHz		8	pF

Figure 11. MAX 7000A Timing Model



The timing characteristics of any signal path can be derived from the timing model and parameters of a particular device. External timing parameters, which represent pin-to-pin timing delays, can be calculated as the sum of internal parameters. Figure 12 shows the timing relationship between internal and external delay parameters.

See *Application Note 94 (Understanding MAX 7000 Timing)* for more information.

Table 20. EPM7064AE Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-4		-7		-10		
			Min	Max	Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.6		1.1		1.4	ns
t_{IO}	I/O input pad and buffer delay			0.6		1.1		1.4	ns
t_{FIN}	Fast input delay			2.5		3.0		3.7	ns
t_{SEXP}	Shared expander delay			1.8		3.0		3.9	ns
t_{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.5		2.5		3.2	ns
t_{LAC}	Logic control array delay			0.6		1.0		1.2	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.3		1.8	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF *(5)*		1.3		1.8		2.3	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.3		6.8	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF *(5)*		4.5		4.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t_{SU}	Register setup time		1.3		2.0		2.9		ns
t_{H}	Register hold time		0.6		1.0		1.3		ns
t_{FSU}	Register setup time of fast input		1.0		1.5		1.5		ns
t_{FH}	Register hold time of fast input		1.5		1.5		1.5		ns
t_{RD}	Register delay			0.7		1.2		1.6	ns
t_{COMB}	Combinatorial delay			0.6		0.9		1.3	ns
t_{IC}	Array clock delay			1.2		1.9		2.5	ns

Table 20. EPM7064AE Internal Timing Parameters (Part 2 of 2) Note (1)

Symbol	Parameter	Conditions	Speed Grade						Unit
			-4		-7		-10		
			Min	Max	Min	Max	Min	Max	
t_{EN}	Register enable time			0.6		1.0		1.2	ns
t_{GLOB}	Global control delay			1.0		1.5		2.2	ns
t_{PRE}	Register preset time			1.3		2.1		2.9	ns
t_{CLR}	Register clear time			1.3		2.1		2.9	ns
t_{PIA}	PIA delay	*(2)*		1.0		1.7		2.3	ns
t_{LPA}	Low-power adder	*(6)*		3.5		4.0		5.0	ns

Table 23. EPM7256AE External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-5		-7		-10		
			Min	Max	Min	Max	Min	Max	
t_{PD1}	Input to non-registered output	C1 = 35 pF *(2)*		5.5		7.5		10	ns
t_{PD2}	I/O input to non-registered output	C1 = 35 pF *(2)*		5.5		7.5		10	ns
t_{SU}	Global clock setup time	*(2)*	3.9		5.2		6.9		ns
t_{H}	Global clock hold time	*(2)*	0.0		0.0		0.0		ns
t_{FSU}	Global clock setup time of fast input		2.5		3.0		3.0		ns
t_{FH}	Global clock hold time of fast input		0.0		0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.5	1.0	4.8	1.0	6.4	ns
t_{CH}	Global clock high time		2.0		3.0		4.0		ns
t_{CL}	Global clock low time		2.0		3.0		4.0		ns
t_{ASU}	Array clock setup time	*(2)*	2.0		2.7		3.6		ns
t_{AH}	Array clock hold time	*(2)*	0.2		0.3		0.5		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	5.4	1.0	7.3	1.0	9.7	ns
t_{ACH}	Array clock high time		2.0		3.0		4.0		ns
t_{ACL}	Array clock low time		2.0		3.0		4.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	2.0		3.0		4.0		ns
t_{CNT}	Minimum global clock period	*(2)*		5.8		7.9		10.5	ns
f_{CNT}	Maximum internal global clock frequency	*(2)*, *(4)*	172.4		126.6		95.2		MHz
t_{ACNT}	Minimum array clock period	*(2)*		5.8		7.9		10.5	ns
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	172.4		126.6		95.2		MHz

Table 24. EPM7256AE Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-5		-7		-10		
			Min	Max	Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.7		0.9		1.2	ns
t_{IO}	I/O input pad and buffer delay			0.7		0.9		1.2	ns
t_{FIN}	Fast input delay			2.4		2.9		3.4	ns
t_{SEXP}	Shared expander delay			2.1		2.8		3.7	ns
t_{PEXP}	Parallel expander delay			0.3		0.5		0.6	ns
t_{LAD}	Logic array delay			1.7		2.2		2.8	ns
t_{LAC}	Logic control array delay			0.8		1.0		1.3	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		0.9		1.2		1.6	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF *(5)*		1.4		1.7		2.1	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.9		6.2		6.6	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF *(5)*		4.5		4.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t_{SU}	Register setup time		1.5		2.1		2.9		ns
t_{H}	Register hold time		0.7		0.9		1.2		ns
t_{FSU}	Register setup time of fast input		1.1		1.6		1.6		ns
t_{FH}	Register hold time of fast input		1.4		1.4		1.4		ns
t_{RD}	Register delay			0.9		1.2		1.6	ns
t_{COMB}	Combinatorial delay			0.5		0.8		1.2	ns

Table 26. EPM7512AE Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-7		-10		-12		
			Min	Max	Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.7		0.9		1.0	ns
t_{IO}	I/O input pad and buffer delay			0.7		0.9		1.0	ns
t_{FIN}	Fast input delay			3.1		3.6		4.1	ns
t_{SEXP}	Shared expander delay			2.7		3.5		4.4	ns
t_{PEXP}	Parallel expander delay			0.4		0.5		0.6	ns
t_{LAD}	Logic array delay			2.2		2.8		3.5	ns
t_{LAC}	Logic control array delay			1.0		1.3		1.7	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		1.0		1.5		1.7	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF *(5)*		1.5		2.0		2.2	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		6.0		6.5		6.7	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		5.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF *(5)*		4.5		5.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 3.3 V	C1 = 35 pF		9.0		10.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		5.0		5.0	ns
t_{SU}	Register setup time		2.1		3.0		3.5		ns
t_{H}	Register hold time		0.6		0.8		1.0		ns
t_{FSU}	Register setup time of fast input		1.6		1.6		1.6		ns
t_{FH}	Register hold time of fast input		1.4		1.4		1.4		ns
t_{RD}	Register delay			1.3		1.7		2.1	ns
t_{COMB}	Combinatorial delay			0.6		0.8		1.0	ns

Table 26. EPM7512AE Internal Timing Parameters (Part 2 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-7		-10		-12		
			Min	Max	Min	Max	Min	Max	
t_{IC}	Array clock delay			1.8		2.3		2.9	ns
t_{EN}	Register enable time			1.0		1.3		1.7	ns
t_{GLOB}	Global control delay			1.7		2.2		2.7	ns
t_{PRE}	Register preset time			1.0		1.4		1.7	ns
t_{CLR}	Register clear time			1.0		1.4		1.7	ns
t_{PIA}	PIA delay	*(2)*		3.0		4.0		4.8	ns
t_{LPA}	Low-power adder	*(6)*		4.5		5.0		5.0	ns

Table 27. EPM7128A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade								Unit
			-6		-7		-10		-12		
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{PD1}	Input to non-registered output	C1 = 35 pF *(2)*		6.0		7.5		10.0		12.0	ns
t_{PD2}	I/O input to non-registered output	C1 = 35 pF *(2)*		6.0		7.5		10.0		12.0	ns
t_{SU}	Global clock setup time	*(2)*	4.2		5.3		7.0		8.5		ns
t_{H}	Global clock hold time	*(2)*	0.0		0.0		0.0		0.0		ns
t_{FSU}	Global clock setup time of fast input		2.5		3.0		3.0		3.0		ns
t_{FH}	Global clock hold time of fast input		0.0		0.0		0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.7	1.0	4.6	1.0	6.1	1.0	7.3	ns
t_{CH}	Global clock high time		3.0		3.0		4.0		5.0		ns
t_{CL}	Global clock low time		3.0		3.0		4.0		5.0		ns
t_{ASU}	Array clock setup time	*(2)*	1.9		2.4		3.1		3.8		ns
t_{AH}	Array clock hold time	*(2)*	1.5		2.2		3.3		4.3		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	6.0	1.0	7.5	1.0	10.0	1.0	12.0	ns
t_{ACH}	Array clock high time		3.0		3.0		4.0		5.0		ns
t_{ACL}	Array clock low time		3.0		3.0		4.0		5.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	3.0		3.0		4.0		5.0		ns
t_{CNT}	Minimum global clock period	*(2)*		6.9		8.6		11.5		13.8	ns
f_{CNT}	Maximum internal global clock frequency	*(2)*, *(4)*	144.9		116.3		87.0		72.5		MHz
t_{ACNT}	Minimum array clock period	*(2)*		6.9		8.6		11.5		13.8	ns
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	144.9		116.3		87		72.5		MHz

Table 30. EPM7256A Internal Timing Parameters (Part 2 of 2) Note (1)

Symbol	Parameter	Conditions	Speed Grade								Unit
			-6		-7		-10		-12		
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{COMB}	Combinatorial delay			1.6		2.0		2.7		3.2	ns
t_{IC}	Array clock delay			2.7		3.4		4.5		5.4	ns
t_{EN}	Register enable time			2.5		3.1		4.2		5.0	ns
t_{GLOB}	Global control delay			1.1		1.4		1.8		2.2	ns
t_{PRE}	Register preset time			2.3		2.9		3.8		4.6	ns
t_{CLR}	Register clear time			2.3		2.9		3.8		4.6	ns
t_{PIA}	PIA delay	(2)		1.3		1.6		2.1		2.6	ns
t_{LPA}	Low-power adder	(6)		11.0		10.0		10.0		10.0	ns

Notes to tables:

(1) These values are specified under the recommended operating conditions shown in Table 14 on page 28. See Figure 12 for more information on switching waveforms.

(2) These values are specified for a PIA fan-out of one LAB (16 macrocells). For each additional LAB fan-out in these devices, add an additional 0.1 ns to the PIA timing value.

(3) This minimum pulse width for preset and clear applies for both global clear and array controls. The t_{LPA} parameter must be added to this minimum width if the clear or reset signal incorporates the t_{LAD} parameter into the signal path.

(4) This parameter is measured with a 16-bit loadable, enabled, up/down counter programmed into each LAB.

(5) Operating conditions: $V_{CCIO} = 2.5 \pm 0.2$ V for commercial and industrial use.

(6) The t_{LPA} parameter must be added to the t_{LAD}, t_{LAC}, t_{IC}, t_{EN}, t_{SEXP}, $\mathbf{t_{ACL}}$, and $\mathbf{t_{CPPW}}$ parameters for macrocells running in low-power mode.

Power Consumption

Supply power (P) versus frequency ($\mathbf{f_{MAX}}$, in MHz) for MAX 7000A devices is calculated with the following equation:

$$P = P_{INT} + P_{IO} = I_{CCINT} \times V_{CC} + P_{IO}$$

The P_{IO} value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Application Note 74 (Evaluating Power for Altera Devices)*.

The I_{CCINT} value depends on the switching frequency and the application logic. The I_{CCINT} value is calculated with the following equation:

$$I_{CCINT} =$$

$$(A \times MC_{TON}) + [B \times (MC_{DEV} - MC_{TON})] + (C \times MC_{USED} \times \mathbf{f_{MAX}} \times \mathbf{tog_{LC}})$$

Figure 15. 49-Pin Ultra FineLine BGA Package Pin-Out Diagram

Package outlines not drawn to scale.

Figure 16. 84-Pin PLCC Package Pin-Out Diagram

Package outline not drawn to scale.

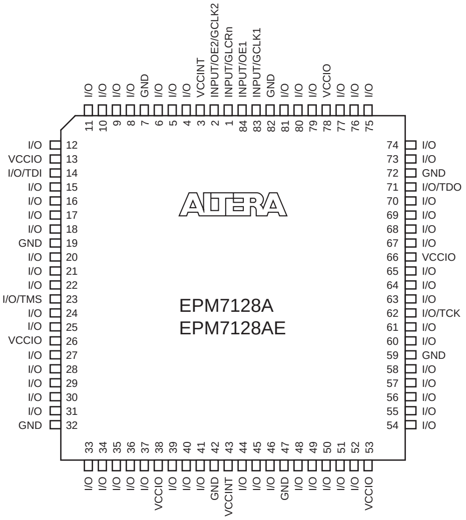


Figure 17. 100-Pin TQFP Package Pin-Out Diagram

Package outline not drawn to scale.

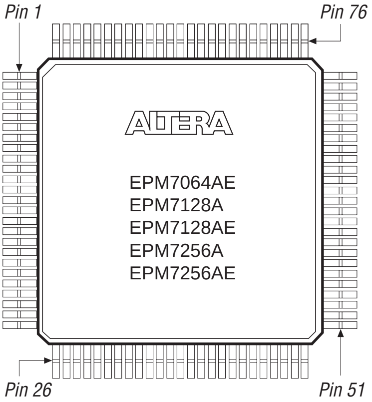


Figure 18. 100-Pin FineLine BGA Package Pin-Out Diagram

Package outline not drawn to scale.

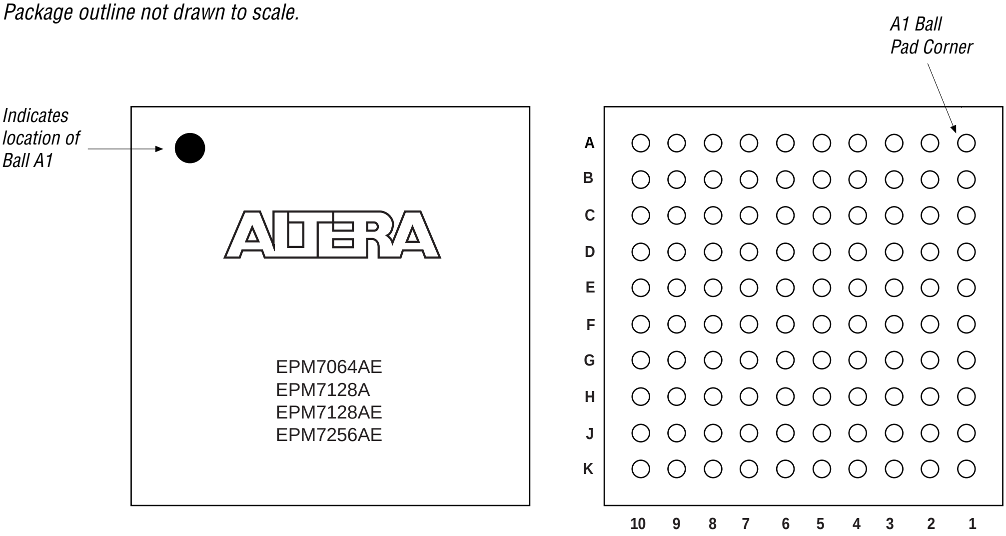


Figure 19. 144-Pin TQFP Package Pin-Out Diagram

Package outline not drawn to scale.

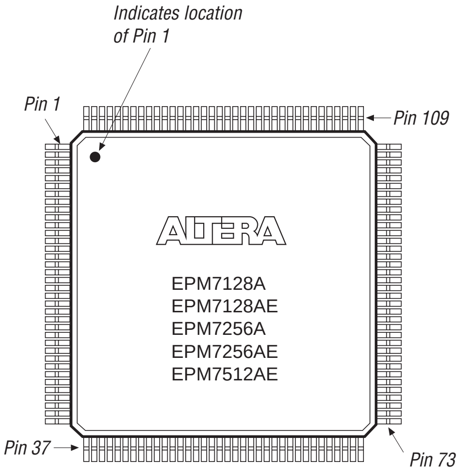


Figure 20. 169-Pin Ultra FineLine BGA Package Pin-Out Diagram

Package outline not drawn to scale.

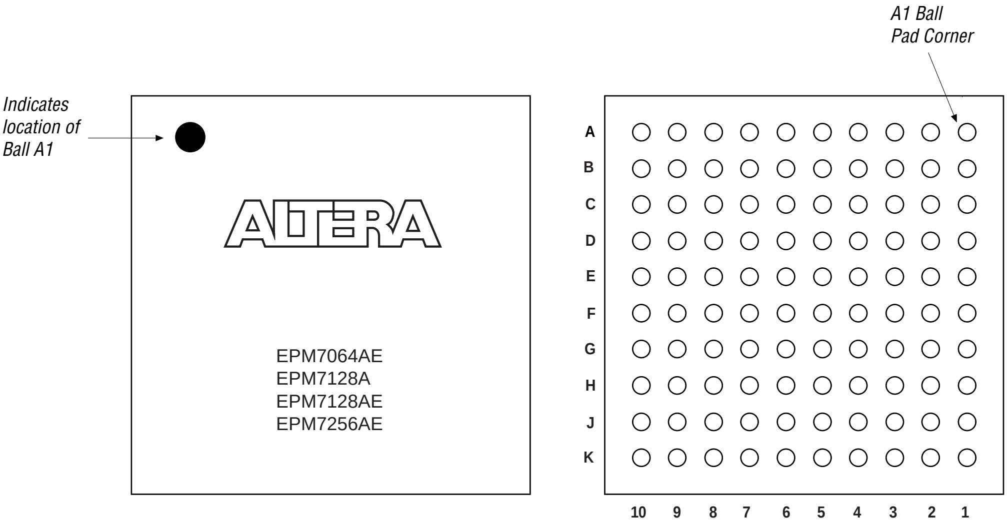


Figure 23. 256-Pin FineLine BGA Package Pin-Out Diagram

Package outline not drawn to scale.

Revision History

The information contained in the *MAX 7000A Programmable Logic Device Data Sheet* version 4.5 supersedes information published in previous versions.

Version 4.5

The following changes were made in the *MAX 7000A Programmable Logic Device Data Sheet* version 4.5:

- Updated text in the "Power Sequencing & Hot-Socketing" section.

Version 4.4

The following changes were made in the *MAX 7000A Programmable Logic Device Data Sheet* version 4.4:

- Added Tables 5 through 7.
- Added "Programming Sequence" on page 17 and "Programming Times" on page 18.